

PJQ1912

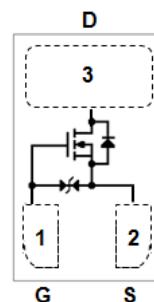
60V N-Channel Enhancement Mode MOSFET – ESD Protected

Voltage **60 V** **Current** **410 mA**

Features

- $R_{DS(ON)}$, $V_{GS}=10V$, $I_D=200mA < 3\Omega$
- $R_{DS(ON)}$, $V_{GS}=4.5V$, $I_D=100mA < 4\Omega$
- Advanced Trench Process Technology
- ESD Protected 2KV HBM
- Specially Designed for Switch Load
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

DFN1006-3L



Mechanical Data

- Case : DFN1006-3L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.00002 ounces, 0.0007 grams

Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^(Note 4)	I_D	410	mA
		330	
Pulsed Drain Current ^(Note 1)	I_{DM}	800	mW
Power Dissipation	P_D	900	
		580	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	°C
Typical Thermal Resistance ^(Note 5)	Junction to Ambient	$R_{\theta JA}$	139 °C/W

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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	60	-	-	V
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	1.0	1.6	2.5	
Drain-Source On-State Resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=200\text{mA}$	-	2.1	3	Ω
		$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=100\text{mA}$	-	2.2	4	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=60\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	± 10	μA
Dynamic ^(Note 6)						
Total Gate Charge	Q_g	$V_{\text{DS}}=30\text{V}, I_{\text{D}}=500\text{mA}, V_{\text{GS}}=10\text{V}^{(\text{Note 2,3})}$	-	1.5	-	nC
Gate-Source Charge	Q_{gs}		-	0.4	-	
Gate-Drain Charge	Q_{gd}		-	0.3	-	
Input Capacitance	C_{iss}	$V_{\text{DS}}=30\text{V}, V_{\text{GS}}=0\text{V}, f=1.0\text{MHz}$	-	20	-	pF
Output Capacitance	C_{oss}		-	8	-	
Reverse Transfer Capacitance	C_{rss}		-	2	-	
Turn-On Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=30\text{V}, I_{\text{D}}=500\text{mA}, V_{\text{GS}}=10\text{V}, R_{\text{G}}=3.3\Omega^{(\text{Note 2,3})}$	-	2	-	ns
Turn-On Rise Time	t_r		-	20	-	
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	5	-	
Turn-Off Fall Time	t_f		-	22	-	
Drain-Source Diode						
Diode Forward Current	I_s	---	-	-	410	mA
Diode Forward Voltage	V_{SD}	$I_s=200\text{mA}, V_{\text{GS}}=0\text{V}$	-	0.86	1.3	V

NOTES :

1. Pulse width $\leq 300\text{us}$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{\text{J(MAX)}}=150^\circ\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_{\text{J}}=25^\circ\text{C}$.
4. The maximum current rating is package limited.
5. R_{eJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

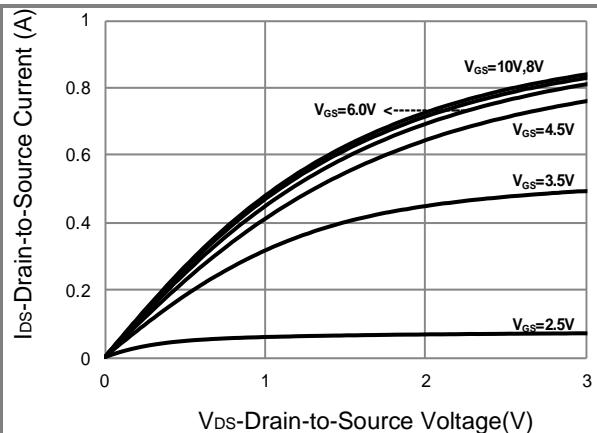


Fig.1 Output Characteristics

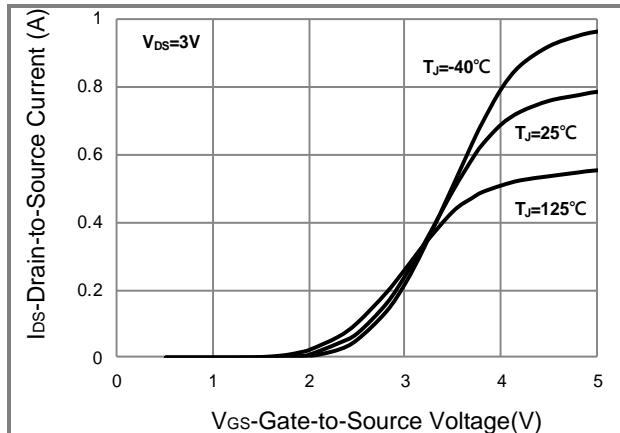


Fig.2 Transfer Characteristics

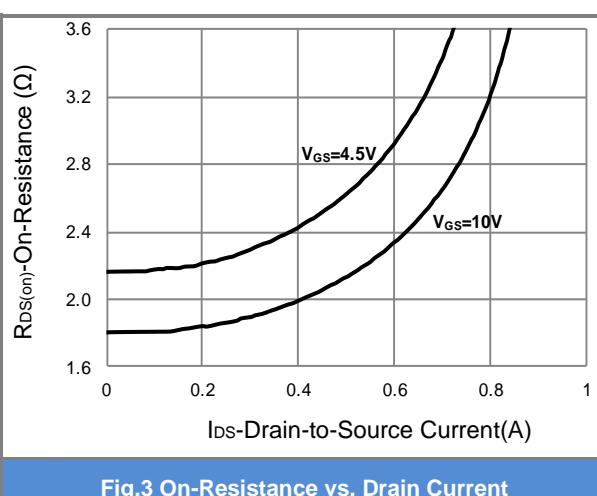


Fig.3 On-Resistance vs. Drain Current

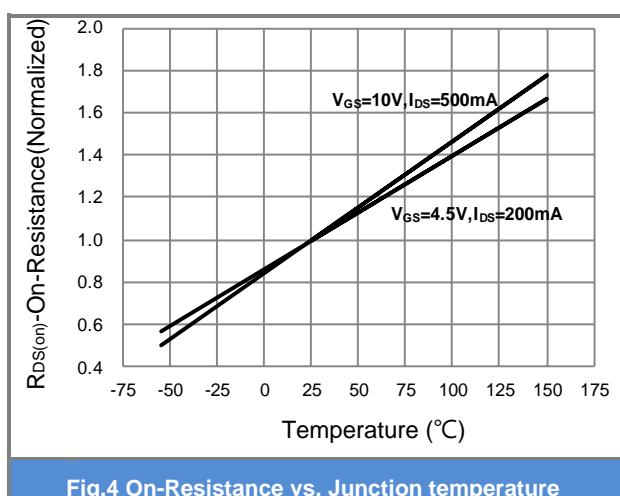


Fig.4 On-Resistance vs. Junction temperature

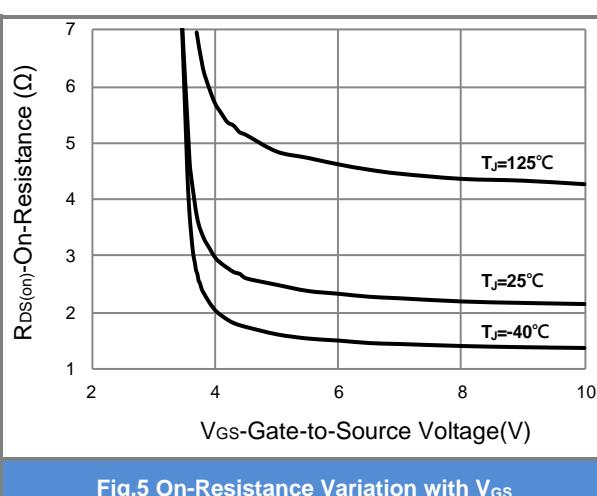


Fig.5 On-Resistance Variation with V_{GS}

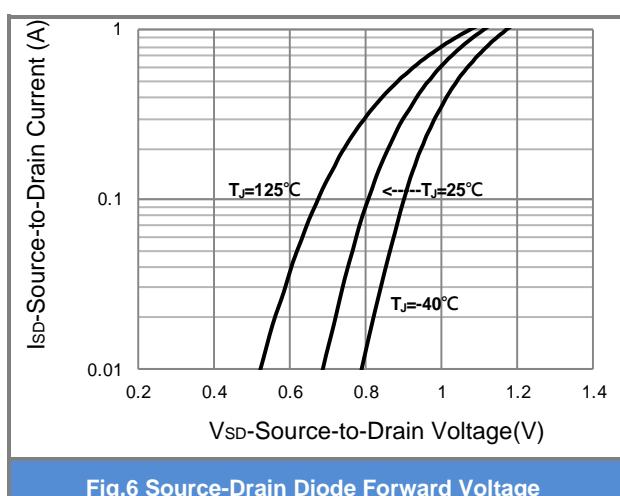


Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES

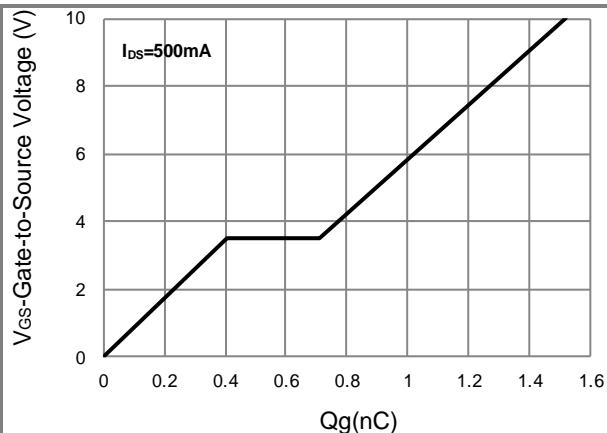


Fig.7 Gate-Charge Characteristics

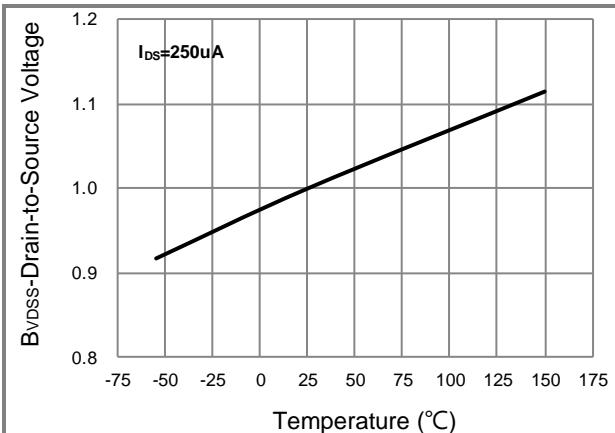


Fig.8 Breakdown Voltage Variation vs. Temperature

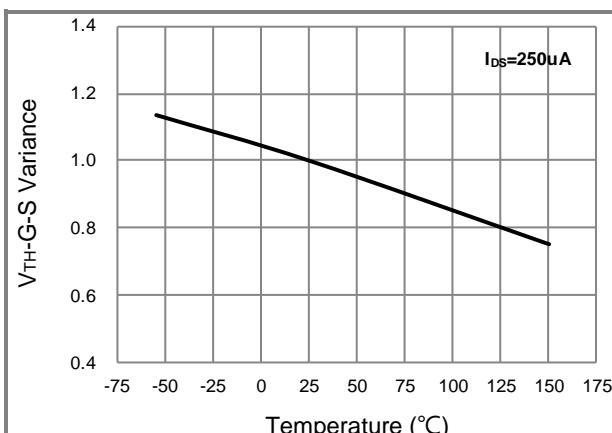


Fig.9 Threshold Voltage Variation with Temperature

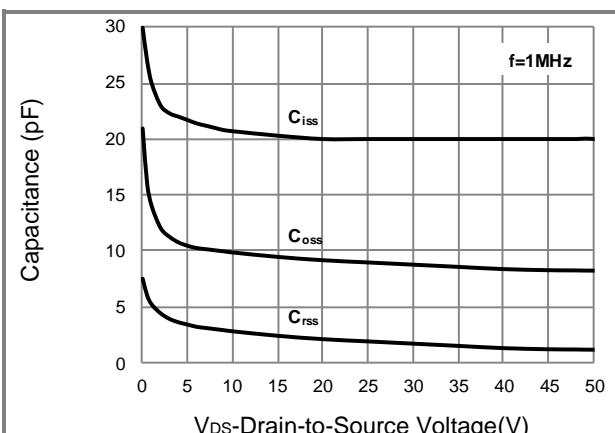


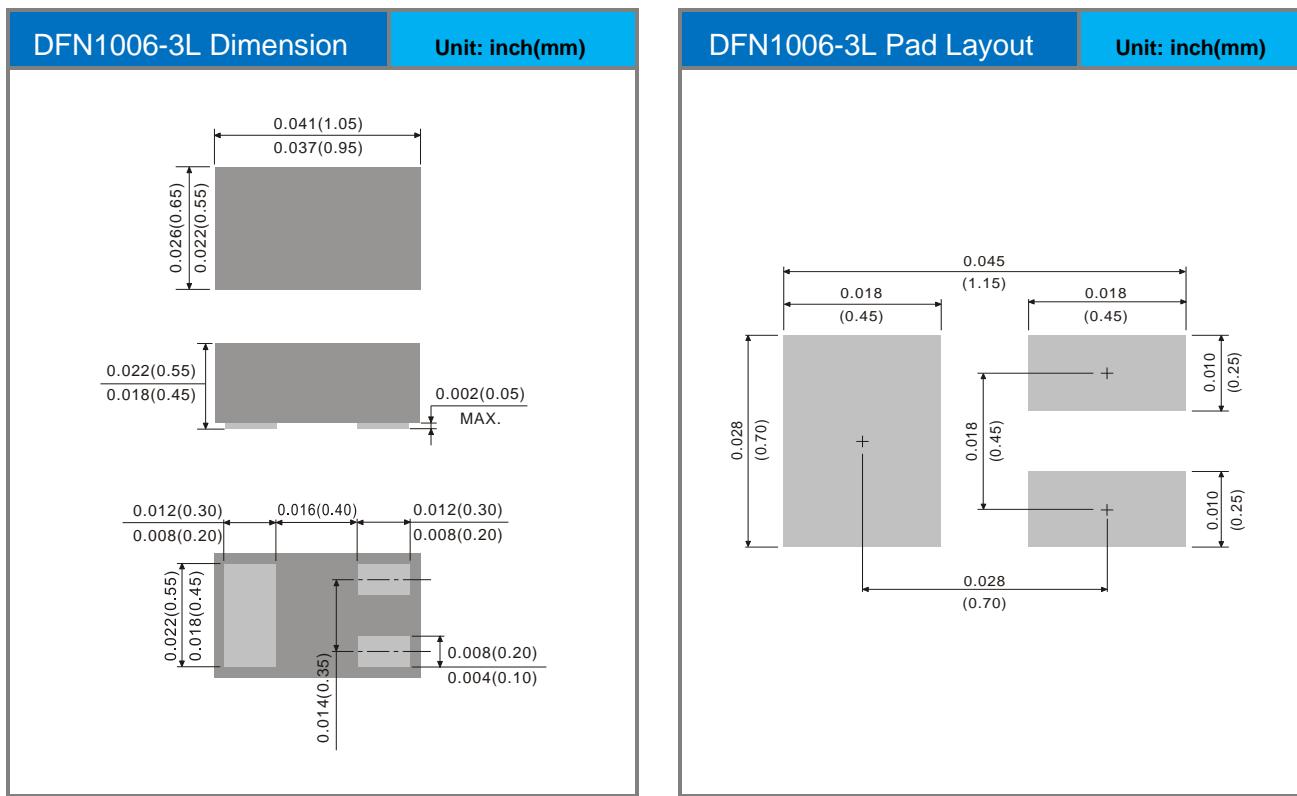
Fig.10 Capacitance vs. Drain-Source Voltage

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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ1912	DFN1006-3L	10K pcs / 7" reel	C

Packaging Information & Mounting Pad Layout



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